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March 2013

FGA20S125P 1200 V, 20 A Shorted-anode IGBT

Features

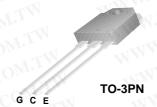
- High Speed Switching
- Low Saturation Voltage: V_{CE(sat)} = 2.0 V @ I_C = 20 A
- High Input Impedance
- RoHS Compliant

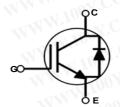
Applications

· Induction Heating, Microwave oven

General Description

Using advanced field stop trench and shorted anode technology, Fairchild[®]'s shorted-anode trench IGBTs offer superior conduction and switching performances for soft switching applications. The device can operate in parallel configuration with exceptional avalanche capability. This device is designed for induction heating and microwave oven.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description		Ratings	Unit	
V _{CES}	Collector to Emitter Voltage	M. TOUX CO.	1250	V. V	
V _{GES}	Gate to Emitter Voltage	MM. TO CO	±25	W. Char	
l _C	Collector Current	$@ T_C = 25^{\circ}C$	40	A O	
ic William	Collector Current	$@ T_C = 100^{\circ}C$	20	N 100 A CO	
I _{CM (1)}	Pulsed Collector Current		60	1100 A	
I _F	Diode Continuous Forward Current	@ T _C = 25°C	40	10A	
I _F	Diode Continuous Forward Current	$@ T_C = 100^{\circ}C$	20	A	
D	Maximum Power Dissipation	$@ T_C = 25^{\circ}C$	250	W	
P_{D}	Maximum Power Dissipation	$@ T_C = 100^{\circ}C$	125	W	
T _J	Operating Junction Temperature		-55 to +175	°C	
T _{stg}	Storage Temperature Range		-55 to +175	°C	
T _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	TINN. I	0.6	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	71V. ±00 *	40	°C/W

Notes:

1: Limited by Tjmax

Package Marking and Ordering Information

Device Marking Device		Package	Reel Size	Tape Width	Quantity	
FGA20S125P	FGA20S125P	TO-3PN	1907.	M.T.V.	30	

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	eteristics (VVIII)					
I _{CES}	Collector Cut-Off Current	V _{CE} = 1250, V _{GE} = 0V	LOV-CC		1	mA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$		DIA.	±500	nA
On Charac	eteristics WWW.CO	M.TW WWV	100 X	COM	TW	
V _{GE(th)}	G-E Threshold Voltage	$I_C = 20$ mA, $V_{CE} = V_{GE}$	4.5	6.0	7.5	V
Y.COM	TW WWW.100X.	$I_C = 20A, V_{GE} = 15V$ $T_C = 25^{\circ}C$	M.100	2.0	2.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	Itage $I_C = 20A, V_{GE} = 15V,$ $T_C = 125^{\circ}C$	10/1/10	2.22	MTW	V
OOY.COM.TW WWW.100	M.TW WWW.100	I _C = 20A, V _{GE} = 15V, T _C = 175°C	WWW.1	2.44	OM.I	V
V_{FM}	Diode Forward Voltage	$I_F = 20A, T_C = 25^{\circ}C$	WWW	1.75	2.4	V
FINI	COM THE TOTAL	I _F = 20A, T _C = 175°C		2.22	COM	V
W.100Y	WILMON WILMON	1007. COW: LA		W.1003	CON	T. T. Y.
- AM	Characteristics	100Y.C M.TW	WW.	100	7.0	VIII.
C _{ies}	Input Capacitance	$V_{CE} = 30V_{V_{GE}} = 0V_{V_{CE}}$	-111	1360	01.00	pF
C _{oes}	Output Capacitance	f = 1MHz	- 31	40	my.C	pF
C _{res}	Reverse Transfer Capacitance	W.100 COM.	-	26	00 -	pF
Switching	Characcteristics					
t _{d(on)}	Turn-On Delay Time	M.100 CONT.1		10	1.700	ns
t _r	Rise Time	$V_{CC} = 600V, I_{C} = 20A,$ $R_{G} = 10\Omega, V_{GE} = 15V,$	-	260	W. 100	ns
t _{d(off)}	Turn-Off Delay Time		- W	400	100	ns
t _f	Fall Time		-W-	100	NAA.	ns
E _{on}	Turn-On Switching Loss	Resistive Load, T _C = 25°C		0.74	MANT	mJ
E _{off}	Turn-Off Switching Loss	M. 1. 100 1. COL	1.1.	0.50	www.	mJ
E _{ts}	Total Switching Loss	WW 1007.00	M.T.W	1.24	- TAN	mJ
t _{d(on)}	Turn-On Delay Time	MMM. TOUX'CO	WILL	11	4134	ns
t _r	Rise Time	WWW.Ioov.C	Ohr-	320	1411	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 600V, I_{C} = 20A,$	OM	420		ns
t _f	Fall Time	$R_G = 10\Omega$, $V_{GE} = 15V$, Resistive Load, $T_C = 175^{\circ}C$	T.MOD	250	3,,	ns
E _{on}	Turn-On Switching Loss			0.94	-44	mJ
E _{off}	Turn-Off Switching Loss	M MMM.	V.Com.	1.23	- 4	mJ
E _{ts}	Total Switching Loss	M. M. Jun	V.CON	2.17	-	mJ
Q _g	Total Gate Charge	LA. W. MIN'10	70	129	-	nC
Q _{ge}	Gate to Emitter Charge	$V_{CE} = 600V, I_{C} = 20A,$	001.	9	-	nC
Q _{gc}	Gate to Collector Charge	V _{GE} = 15V	100 F.C.	66	N _	nC

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

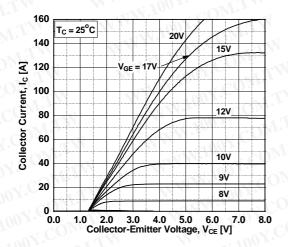


Figure 3. Typical Saturation Voltage Characteritics

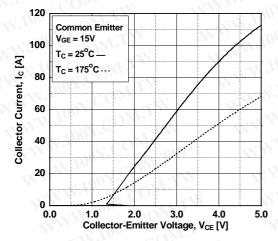


Figure 5. Saturation Voltage vs. Case

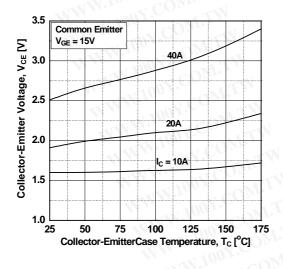


Figure 2. Typical Saturation Voltage Characteristics

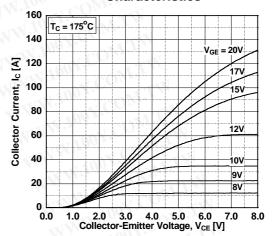


Figure 4. Transfer Characteristics

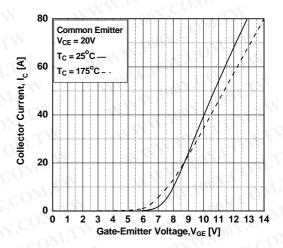
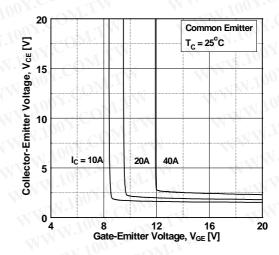


Figure 6. Saturation Voltage vs. Vge



Typical Performance Characteristics

Figure 7. Saturation Voltage vs. Vge

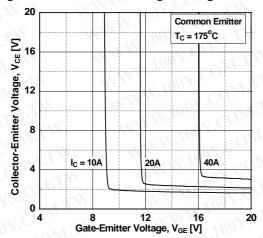


Figure 9. Gate Charge Characteristics

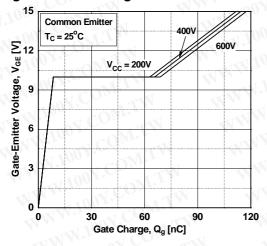


Figure 11. Turn-On Characteristics vs Gate Resistance

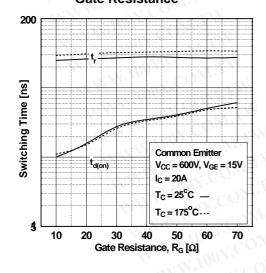


Figure 8. Capacitance Characteristics

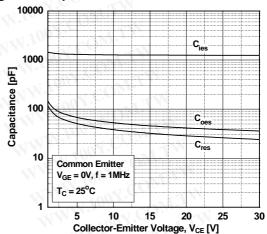


Figure 10. SOA Characteristics

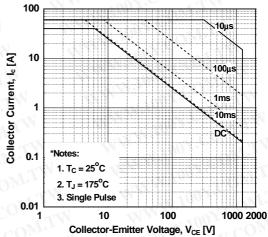
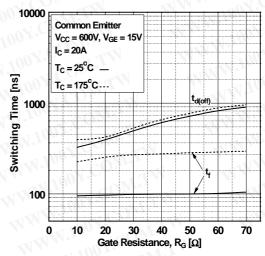


Figure 12. Turn-off Characteristics vs.

Gate Resistance



Typical Performance Characteristics

Figure 13. Turn-on Characteristics VS.
Collector Current

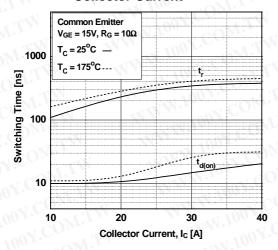


Figure 14.Turn-off Characteristics VS.
Collector Current

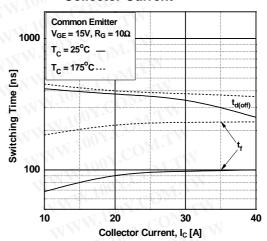


Figure 15. Switching Loss VS. Gate Resistance

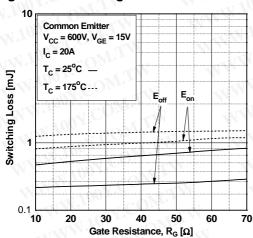


Figure 16. Switching Loss VS. Collector Current

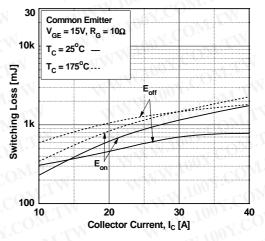


Figure 17. Turn off Switching SOA Characteristics

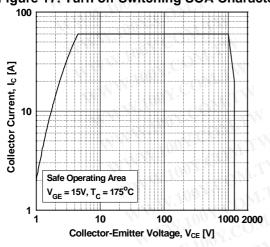
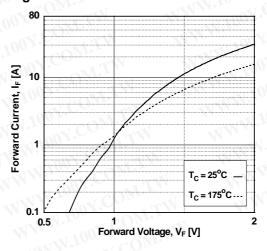


Figure 18. Forward Characteristics



WWW.100Y.COM.TW Figure 19. Transient Thermal Impedance of IGBT

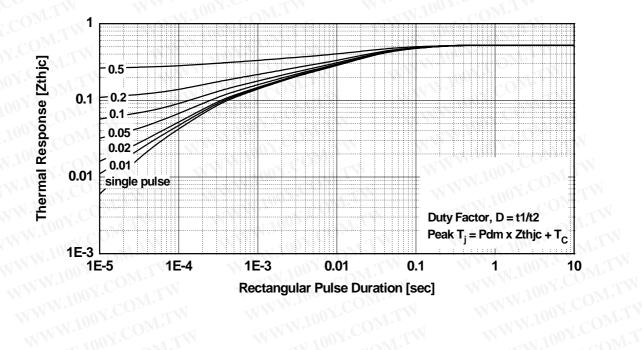
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Mechanical Dimensions 4.60 1,65 1,45 20.10 19,70 18.90 18,50 WWW.1007. (1.85) 2,20 1.80 ф Ø0.55(M) 1.20 0.80 5,45 (R0,50) Dimensions in Millimeters



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